## **AMENDMENTS**

## In the Claims

This listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently amended): A method to optimize a signal routing in an integrated circuit comprising:

providing a signal routing in an integrated circuit layout wherein said signal routing comprises a configuration of metal lines in a stack of metal levels and wherein each said metal is separated from an underlying substrate by dielectric material;

thereafter calculating a Joule heating estimate for said signal routing;

thereafter comparing said Joule heating estimate to a standard value;

thereafter updating said signal routing if said Joule heating estimate exceeds said standard value wherein said updating comprises generating a new configuration of said metal lines in said metal levels and wherein said new configuration reduces said Joule heating; and

thereafter repeating said steps of calculating, comparing, and updating if said Joule heating estimate still exceeds said standard value;

wherein said step of updating said signal routing comprises reducing a total volume of said dielectric material between said metal lines and said substrate.

2. (Original) The method according to Claim 1 wherein said metal lines comprise copper.

- 3. (Original) The method according to Claim 1 wherein said steps of updating said signal routing is performed by an automating routing system.
- 4. (Original) The method according to Claim 1 wherein said step of calculating a Joule heating estimate comprises a calculation based on current density in said metal lines and thermal conductivity of said dielectric material.
- 5. (Original) The method according to Claim 1 wherein said metal lines are formed by a damascene process.
  - 6. (Cancelled)
- 7. (Original) The method according to Claim 1 wherein said step of updating said signal routing comprises coupling said metal lines to a floating diffusion region in said substrate.
- 8. (Original) The method according to Claim 7 wherein said substrate comprises a ptype doping and said floating diffusion region comprises an n-type doping.
- 9. (Original) The method according to Claim 1 wherein said step of updating said signal routing comprises connecting said signal routing metal lines to a metal heat sink wherein said metal heat sink comprises a set of metal lines that are connected together by vias to create a large thermal mass.

10. (Original) The method according to Claim 9 wherein said set of metal lines are formed in metal levels lower than said signal routing metal lines.

11. (Currently amended) A method to design an integrated circuit device comprising: generating an integrated circuit layout comprising a plurality circuit elements and signal nodes and comprising a stack of metal levels defining a plurality of signal routings between said signal nodes wherein each said signal routing comprises a configuration of metal lines in said metal levels and wherein each said metal level is separated from an underlying substrate by dielectric material;

thereafter calculating Joule heating estimates for each said signal routing;
thereafter comparing said signal routing Joule heating estimates to a standard value;
and

thereafter updating said signal routings for each said signal routing where said Joule heating estimate exceeds said standard value wherein said updating comprises generating a new configuration of metal lines in said metal levels and wherein said new configurations reduce Joule heating in said signal routings; and

thereafter repeating said steps of calculating, comparing, and updating until all of said Joule heating estimates do not exceed said standard value:

wherein said step of updating said signal routings comprises reducing total volumes of said dielectric material between said metal lines and said substrate.

12. (Original) The method according to Claim 11 wherein said metal lines comprise copper.

- 13. (Original) The method according to Claim 11 wherein said steps of generating an integrated circuit layout and of updating said signal routings are performed by an automating routing system.
- 14. (Original) The method according to Claim 11 wherein said step of calculating Joule heating estimates comprises a calculation based on current density in said metal lines and thermal conductivity of said dielectric material.
- 15. (Original) The method according to Claim 11 wherein said metal lines are formed by a damascene process.

## 16. (Cancelled)

- 17. (Original) The method according to Claim 11 wherein said step of updating said signal routings comprises coupling said metal lines to a floating diffusion region in said substrate.
- 18. (Original) The method according to Claim 17 wherein said substrate comprises a p-type doping and said floating diffusion region comprises an n-type doping.
- 19. (Original) The method according to Claim 11 wherein said step of updating said signal routing comprises connecting said signal routing metal lines to a metal heat sink wherein

said metal heat sink comprises a set of metal lines that are connected together by vias to create a large thermal mass.

- 20. (Original) The method according to Claim 19 wherein said set of metal lines are formed in metal levels lower than said signal routing metal lines.
- 21. (Currently amended) A signal routing structure in an integrated circuit comprising: a first set of metal lines in a stack of metal levels wherein said each metal level is separated from an underlying substrate by dielectric material; and

a heat sink coupled to said first set of metal lines by a via or numbers of vias;

wherein said heat sink comprises a second set of metal lines that are connected together

by vias or numbers of vias; and

said second set of metal lines are formed in metal levels lower than said first set of metal lines;

- 22. (Cancelled)
- 23. (Cancelled)
- 24. (Original) The structure according to Claim 21 wherein said heat sink comprises a floating diffusion region in said substrate.
- 25. (Original) The structure according to Claim 24 wherein said substrate comprises a p-type doping and said floating diffusion region comprises an n-type doping.